

INCHANGE SEMICONDUCTOR

iscN-Channel MOSFET Transistor

TK6A65W, ITK6A65W

FEATURES

- Low drain-source on-resistance: $R_{DS}(ON) = 0.85\Omega$ (typ.)
- Enhancement mode: Vth = 2.5 to 3.5V (VDs = 10 V, ID=0.18mA)
- 100% avalanche tested
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

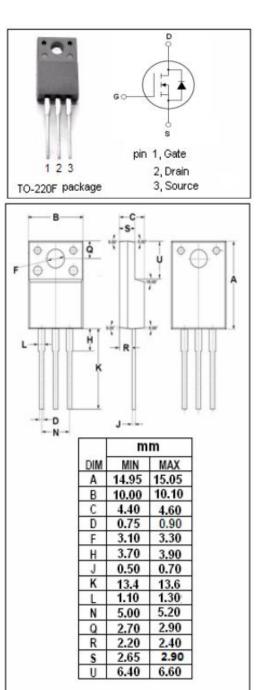
Switching Voltage Regulators

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)							
SYMBOL	PARAMETER	VALUE	UNIT				
V _{DSS}	Drain-Source Voltage	650	V				
V _{GS}	Gate-Source Voltage	±30	V				
lD	Drain Current-Continuous 5		А				
I _{DM}	Drain Current-Single Pulsed	23.2	А				
PD	Total Dissipation @Tc=25°C	30	W				
Tj	Max. Operating Junction Temperature	150	°C				
T _{stg}	Storage Temperature	-55~150	°C				

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	4.17	°C /W
Rth(ch-a)	(ch-a) Channel-to-ambient thermal resistance		°C/W

1





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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 10mA	650			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = 10V; I _D =0.18mA	2.5		3.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =2.9A		850	1000	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} =0V			±1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 650V; V _{GS} = 0V			10	μA
V _{SDF}	Diode forward voltage	I _{DR} =5.8A, V _{GS} = 0 V			1.7	V

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2